Attorney's Docket No.: 12732-061002 / US5111D1

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Taketomi Asami et al. Art Unit: Unknown Serial No.: New Divisional Application Examiner: Unknown

Filed : March 4, 2004

Title : SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE

SAME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **INFORMATION DISCLOSURE STATEMENT**

Under 35 USC §120, this application relies on the earlier filing date of application serial number 09/918,547, filed on August 1, 2001. The attached list of references were submitted to and/or cited by the Office in the prior application and, therefore, are not provided in this application.

This statement is being filed with the application. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: March 4, 2004

John F. Hayden

Reg. No. 37,640

Customer No. 26171
Fish & Richardson P.C.
1425 K Street, N.W., 11th Floor
Washington, DC 20005-3500
Telephone: (202) 783-5070
Facsimile: (202) 783-2331

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U.S. Department of Commerce Patent and Trademark Office Attorney's Docket No. 12732-061002

Application No. New Divisional Application

## Information Disclosure Statement by Applicant

(Use several sheets if necessary)

(37 CFR §1.98(b))

Applicant

Taketomi Asami et al.

Filing Date
March 4, 2004

Group Art Unit

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Examiner Signature

Date Considered

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Substitute Form PTO-1449 (Modified)  U.S. Department of Commerce Patent and Trademark Office  Information Disclosure Statement by Applicant (Use several sheets if necessary)  (37 CFR §1.98(b))			Attorney's Docket No. 12732-061002		Application No. New Division Application	nal	
			Applicant Taketomi Asami et al.				
			Filing Date Group Art Unit March 4, 2004				
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